



DMT6009LCT

Product Summary

BV _{DSS}	R _{DS(ON)} Max	Ι _D T _C = +25°C		
60V	12mΩ @V _{GS} = 10V	37.2A		
	14.5mΩ @V _{GS} = 4.5V	33.9A		

Description and Applications

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high-efficiency power management applications.

- DC-DC Converters
- Power Management Functions
- Load Switch

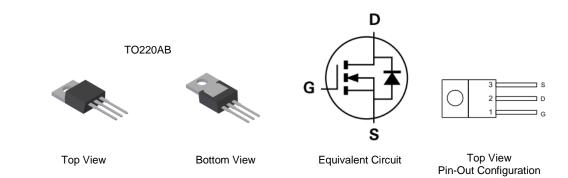
60V N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Excellent Q_{GD X} R_{DS(ON)} Product (FOM)
- Advanced Technology for DC-DC Converts
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: TO220AB
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMT6009LCT	TO220AB	50 Pieces/Tube

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

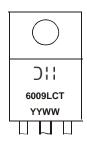
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



) | |=Manufacturer's Marking 6009LCT = Product Type Marking CodeYYWW = Date Code Marking YY or <u>YY</u> = Last Digit of Year (ex: 16 = 2016) WW or <u>WW</u> = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage		V _{DSS}	60	V
Gate-Source Voltage		V _{GSS}	±16	V
Continuous Drain Current (Note 6) V_{GS} = 10V	T _C = +25°C T _C = +100°C	ID	37.2 29.8	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	80	A
Maximum Body Diode Forward Current (Note 6)		Is	80	A
Avalanche Current, L = 0.1mH		las	19.8	A
Avalanche Energy, L = 0.1mH		E _{AS}	19.6	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.2	W
Thermal Resistance, Junction to Ambient (Note 5)		R _{0JA}	55	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	25	W
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	5	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

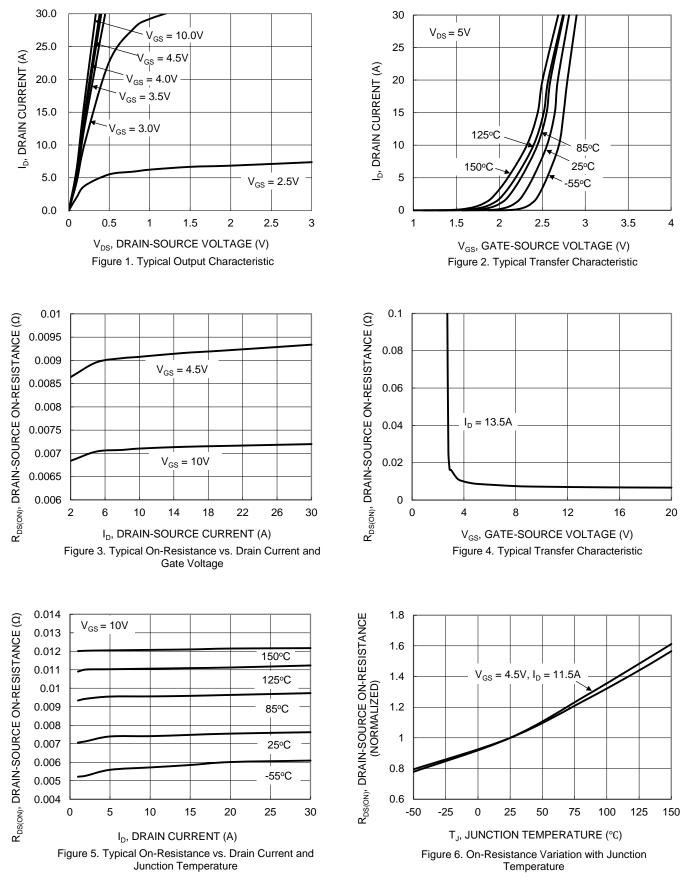
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Symbol	IVIIII	тур	INIAA	Unit	Test condition	
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	V _{GS} = 0V, I _D = 250µA	
Zero Gate Voltage Drain Current	IDSS			1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage				±100	nA	$V_{\rm DS} = \pm 16V, V_{\rm DS} = 0V$ $V_{\rm GS} = \pm 16V, V_{\rm DS} = 0V$	
ON CHARACTERISTICS (Note 7)	I _{GSS}			100		$VGS = \pm 10V, VDS = 0V$	
Gate Threshold Voltage	V _{GS(TH)}	0.7		2	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
, ,		_	9.4	12	$V_{cc} = 10V$	$V_{GS} = 10V, I_D = 13.5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		7.6	14.5	mΩ	$V_{GS} = 4.5V, I_D = 11.5A$	
Diode Forward Voltage	V _{SD}	_	_	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)						<u> </u>	
Input Capacitance	C _{ISS}	_	1,925			$V_{DS} = 30V, f = 1MHz,$	
Output Capacitance	Coss	_	438	_	pF		
Reverse Transfer Capacitance	C _{RSS}	_	41			$V_{GS} = 0V$	
Gate Resistance	R _G		1.7		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q _G	_	15.6				
Total Gate Charge (V _{GS} = 10V)	Q _G		33.5			$V_{DD} = 30V, I_D = 13.5A$	
Gate-Source Charge	Q _{GS}		4.7		nC		
Gate-Drain Charge	Q _{GD}		5.3				
Turn-On Delay Time	t _{D(ON)}		4.5			$V_{DS} = 30V, V_{GS} = 10V,$ $R_G = 6\Omega, I_D = 13.5A$	
Turn-On Rise Time	t _R		8.6				
Turn-Off Delay Time	t _{D(OFF)}	_	35.9	—	ns		
Turn-Off Fall Time	tF	_	15.7	—	1		
Reverse Recovery Time	t _{RR}	_	18.2		ns		
Reverse Recovery Charge	Q _{RR}	_	33.1	_	nC	$I_F = 13.5A, di/dt = 100A/\mu s$	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Device mounted on an infinite heat sink.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.



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DMT6009LCT Document number: DS38044 Rev. 1 - 2



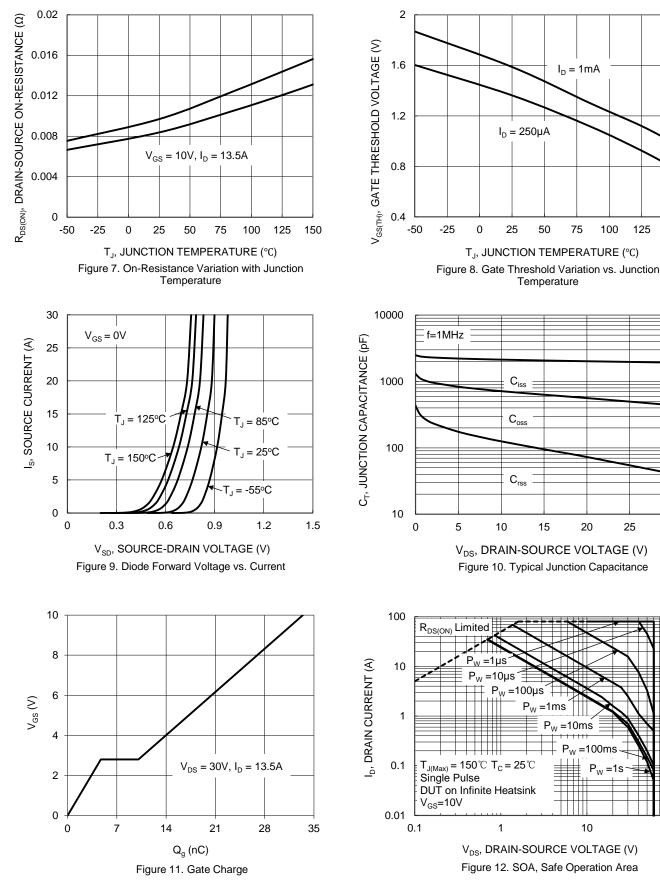
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125

25

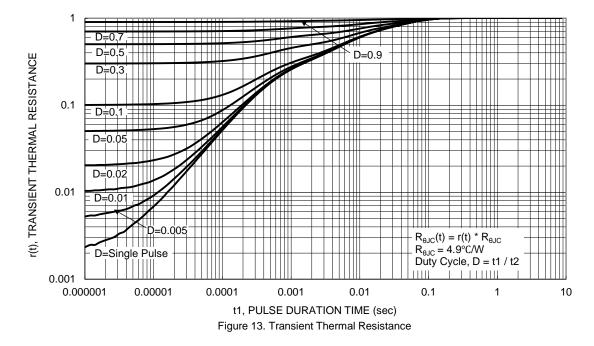
30

150



100

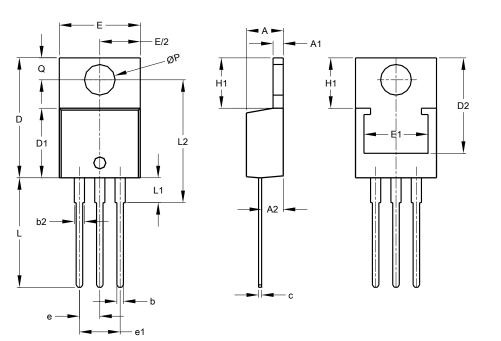






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO220AB

TO220AB					
Dim	Min	Max	Тур		
Α	3.56	4.82	Ι		
A1	0.51	1.39	-		
A2	2.04	2.92	_		
b	0.39	1.01	0.81		
b2	1.15	1.77	1.24		
С	0.356	0.61	-		
D	14.22	16.51	_		
D1	8.39	9.01	Ι		
D2	11.45	12.87	_		
е	-	Ι	2.54		
e1	-	-	5.08		
Е	9.66	10.66	Ι		
E1	6.86	8.89	_		
H1	5.85	6.85	Ι		
L	12.70	14.73	_		
L1	_	6.35	_		
L2	15.80	16.20	16.00		
Р	3.54	4.08	_		
Q	2.54	3.42	_		
All	All Dimensions in mm				



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